BAV23 series

Dual high-voltage switching diodes Rev. 07 — 19 March 2010

Product data sheet

1. **Product profile**

1.1 General description

Dual high-voltage switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number Package		Configuration	
	NXP	JEDEC	
BAV23A	SOT23	TO-236AB	dual common anode
BAV23C	SOT23	TO-236AB	dual common cathode
BAV23S	SOT23	TO-236AB	dual series
BAV23	SOT143B	-	dual isolated

1.2 Features and benefits

- High switching speed: t_{rr} ≤ 50 ns
- Low leakage current
- Repetitive peak reverse voltage: $V_{RRM} \le 250 \text{ V}$
- Low capacitance: C_d ≤ 2 pF
- Small SMD plastic package

1.3 Applications

- High-speed switching at high voltage
- High-voltage general-purpose switching

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	V _R = 200 V	-	-	100	nA
V _R	reverse voltage		-	-	200	V
t _{rr}	reverse recovery time		<u>[1]</u> -	-	50	ns

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



2. Pinning information

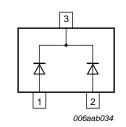
Table 3. Pinning

	9		
Pin	Description	Simplified outline	Graphic symbol
BAV23A			
1	cathode (diode 1)		
2	cathode (diode 2)	3	3
3	common anode	1 2	
			006aab099

R	ΔV/23C	
ш	A 1 2 3 C	

1	anode (diode 1)
2	anode (diode 2)
3	common cathode

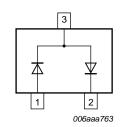




BAV23S

1	anode (diode 1)
2	cathode (diode 2)
3	cathode (diode 1), anode (diode 2)

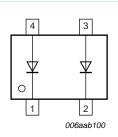




BAV23

1	cathode (diode 1)
2	cathode (diode 2)
3	anode (diode 2)
4	anode (diode 1)





3. Ordering information

Table 4. Ordering information

Type number	Package			
	Name	Description	Version	
BAV23A	-	plastic surface-mounted package; 3 leads	SOT23	
BAV23C				
BAV23S				
BAV23	-	plastic surface-mounted package; 4 leads	SOT143B	

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
BAV23A	*V0
BAV23C	*V9
BAV23S	*V5
BAV23	*L3

^{[1] * = -:} made in Hong Kong

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	250	V
V_R	reverse voltage		-	200	V
I _F	forward current		<u>[1]</u> _	225	mA
			[2] _	125	mA
I _{FRM}	repetitive peak forward current		-	625	mA
I _{FSM}	non-repetitive peak forward	square wave	[3]		
	current	t _p = 1 μs	-	9	Α
		t _p = 100 μs	-	3	Α
		$t_p = 10 \text{ ms}$	-	1.7	Α

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

 Table 6.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[4]</u> _	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Single diode loaded.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] -	-	500	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		-	-	360	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

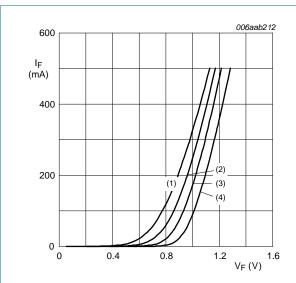
Parameter	Conditions	Min	Тур	Max	Unit
forward voltage	I _F = 100 mA	-	-	1.0	V
	$I_F = 200 \text{ mA}$	-	-	1.25	V
reverse current	V _R = 200 V	-	-	100	nA
	$V_R = 200 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	2	pF
reverse recovery time		<u>[1]</u> _	-	50	ns
	forward voltage reverse current diode capacitance	$I_{F} = 100 \text{ mA}$ $I_{F} = 200 \text{ mA}$ reverse current $V_{R} = 200 \text{ V}$ $V_{R} = 200 \text{ V}; T_{j} = 150 \text{ °C}$ diode capacitance $f = 1 \text{ MHz}; V_{R} = 0 \text{ V}$	$\begin{array}{c} \text{forward voltage} & I_F = 100 \text{ mA} & - \\ I_F = 200 \text{ mA} & - \\ \text{reverse current} & V_R = 200 \text{ V} & - \\ \hline V_R = 200 \text{ V}; T_j = 150 \text{ °C} & - \\ \text{diode capacitance} & \text{f} = 1 \text{ MHz}; V_R = 0 \text{ V} & - \\ \end{array}$		

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 $\Omega;$ measured at I_R = 1 mA.

^[2] Double diode loaded.

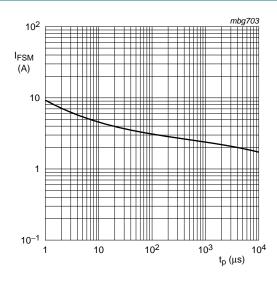
^[3] $T_i = 25$ °C prior to surge.

^[4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

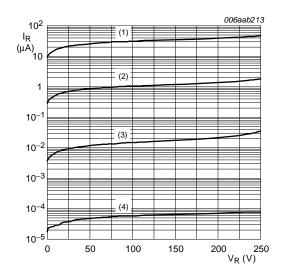
Fig 1. Forward current as a function of forward voltage; typical values



Based on square wave currents.

 $T_i = 25$ °C; prior to surge

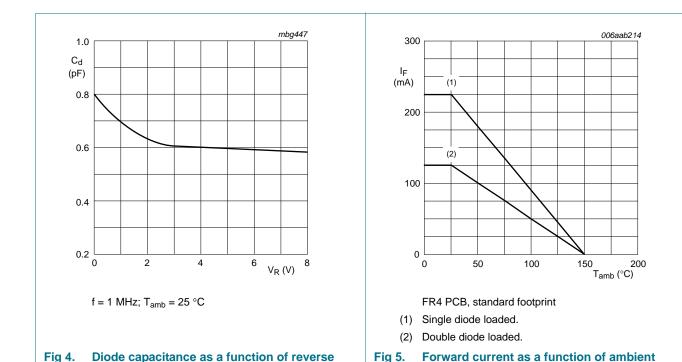
Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

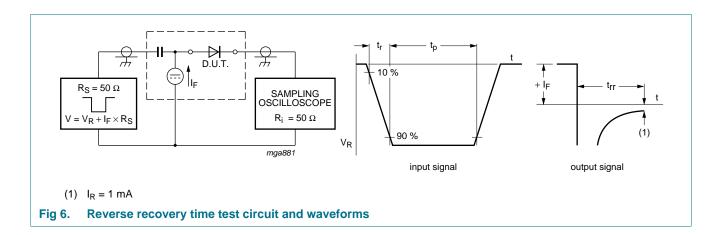
Fig 3. Reverse current as a function of reverse voltage; typical values

temperature; derating curves

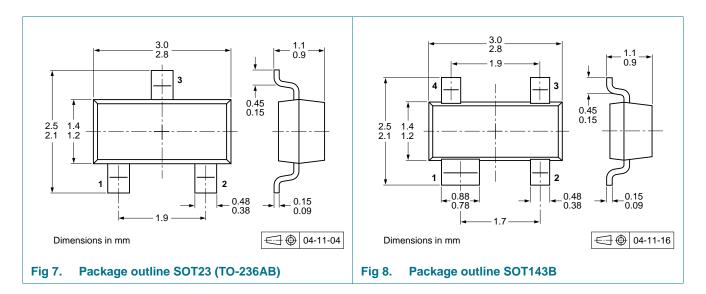


8. Test information

voltage; typical values



9. Package outline



10. Packing information

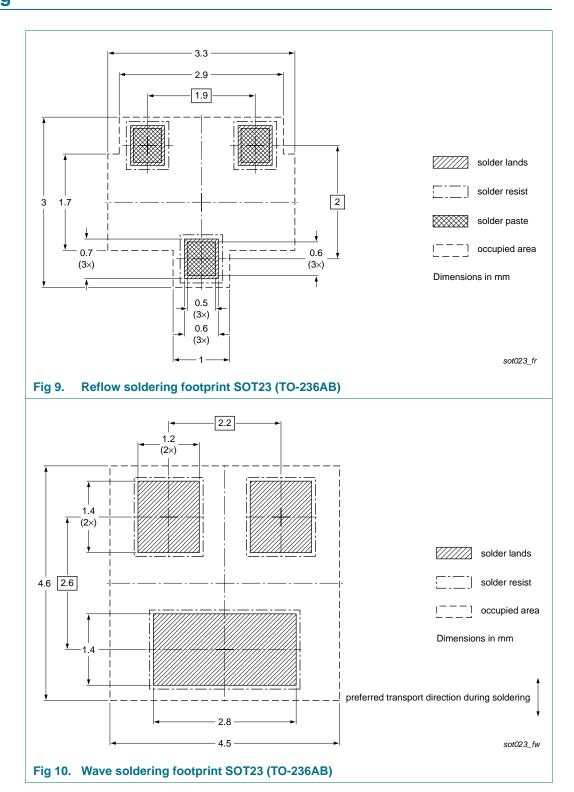
Table 9. Packing methods

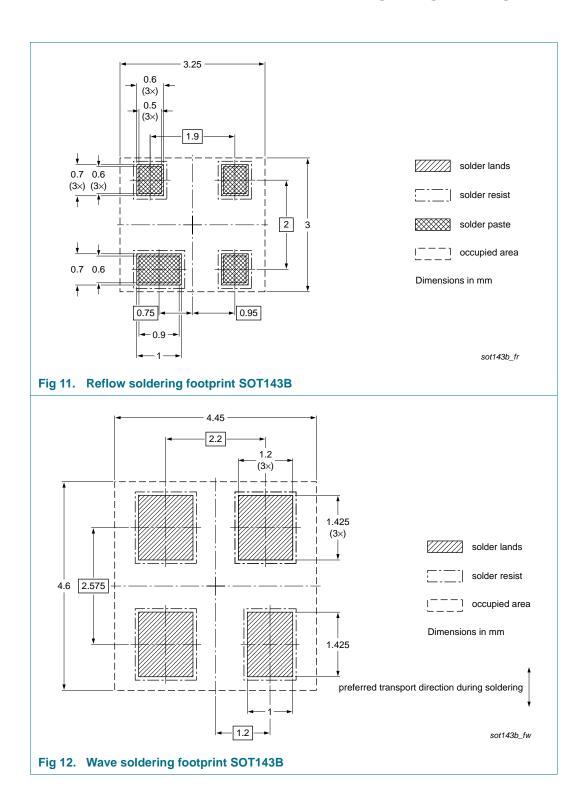
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number Pa	Package	Description	Packing	Packing quantity	
			3000	10000	
BAV23A	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
BAV23C					
BAV23S					
BAV23	SOT143B	4 mm pitch, 8 mm tape and reel	-215	-235	

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering





12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV23_SER_7	20100319	Product data sheet	-	BAV23_SER_6
Modifications:	 Type numbers BAV23A/DG, BAV23C/DG, BAV23S/DG and BAV23/DG deleted Type numbers BAV23A and BAV23C added Table 5 "Marking codes": updated Figure 6: adaptation of test condition to specified characteristics in Table 8 Figure 9, 10, 11 and 12: updated Section 13 "Legal information": updated 			
BAV23_SER_6	20080303	Product data sheet	-	BAV23S_5 BAV23_2
BAV23S_5	20011012	Product specification	-	BAV23S_4
BAV23_2	19960917	Product specification	-	BAV23_1

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAV23 series

Dual high-voltage switching diodes

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